# High Input Voltage, Low Quiescent Current, Low-Dropout Linear Regulator

General Description

The EMP8042 is a high voltage, low quiescent current, low dropout regulator with 150mA output driving capacity. The EMP8042, which operates over an input range up to 20V, is stable with any capacitors, whose capacitance is larger than 1μF, and suitable for powering battery-management ICs because of the virtue of its low quiescent current consumption and low dropout voltage. Below the maximum power dissipation (please refer to Note. 5), It guarantees delivery of 150mA output current, and supports preset output voltages ranging from 1.3V to 6.0V with 0.1V increment for fixed output version, and supports output voltage up to 12V for adjustable output (ADJ) version.

EMP8042 also includes bandgap voltage reference, constant current limiting and thermal overload protection. It's available in SOT-23-5, SOT-89-3 and SOT-23-3 miniature packages.
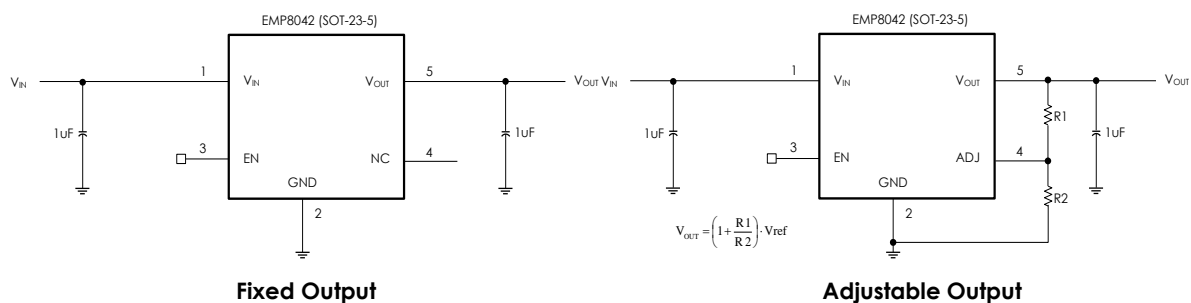
Applications

- Logic Supply for High Voltage Batteries
- Keep-Alive Supply
- 3-4 Cell Li-ion Batteries Powered systems

Features

- 150mA output current driving capacity
- 780mV typical dropout at Io=150mA
- 13μA typical quiescent current
- 1μA typical shutdown mode
- Up to 20V input range
- Stable with small ceramic output capacitors (1μF)
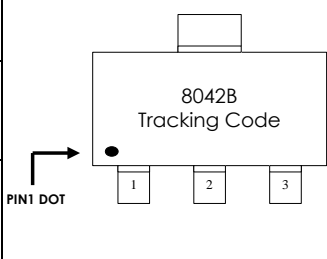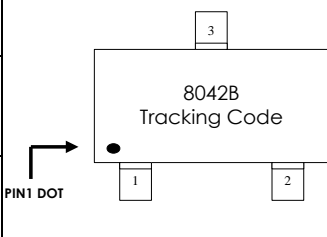- Over temperature and over current protection

Typical Application

$$V_{OUT} = \left(1 + \frac{R1}{R2}\right) \cdot V_{ref}$$

Fixed Output   **Adjustable Output**

Connection Diagrams
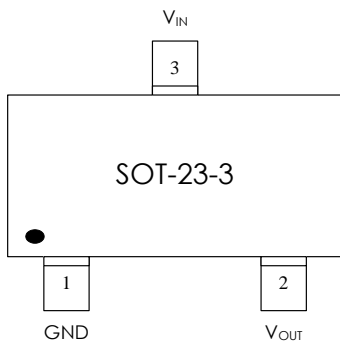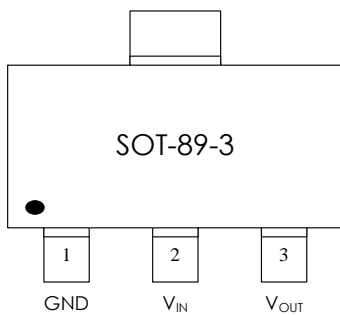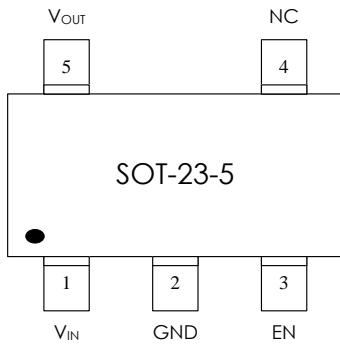
SOT-23-5

Order information

EMP8042B-XXVF05NRR
XX	Output voltage
VF05	SOT-23-5 Package
NRR	RoHS & Halogen free package
	Rating: -40 to 85°C
	Package in Tape & Reel

SOT-89-3

EMP8042B-XXVG03NRR
XX	Output voltage
VG03	SOT-89-3 Package
NRR	RoHS & Halogen free package
	Rating: -40 to 85°C
	Package in Tape & Reel

SOT-23-3

EMP8042B-XXVN03NRR
XX	Output voltage
VN03	SOT-23-3 Package
NRR	RoHS & Halogen free package
	Rating: -40 to 85°C
	Package in Tape & Reel

Order, Marking and Packing Information

Package	Vout	Product ID.	Marking	Packing
SOT-23-5	3.0V	EMP8042B-30VF05NRR	8042B Tracking Code	Tape & Reel 3Kpcs
	3.3V	EMP8042B-33VF05NRR		
	5.0V	EMP8042B-50VF05NRR		

	ADJ	EMP8042B-00VF05NRR		
SOT-89-3	3.0V	EMP8042B-30VG03NRR	8042B Tracking Code	Tape & Reel 1Kpcs
	3.3V	EMP8042B-33VG03NRR		
	5.0V	EMP8042B-50VG03NRR		
SOT-23-3	3.0V	EMP8042B-30VN03NRR	8042B Tracking Code	Tape & Reel 3Kpcs
	3.3V	EMP8042B-33VN03NRR		
	5.0V	EMP8042B-50VN03NRR		

Pin Functions

Name	SOT-23-5	SOT-89-3	SOT23-3	Function
V_{IN}	1	2	3	**Supply Voltage Input** Require a minimum input capacitor of close to 1µF to ensure stability and sufficient decoupling from the ground pin.
GND	2	1	1	**Ground Pin**
EN	3	N/A	N/A	**Shutdown Input** The EN pin is pulled "High" internally. Set the regulator into the disable mode by pulling the EN pin low.
ADJ	4	N/A	N/A	**Adjust:** Feedback input. Connect to resistive voltage-divider network. $V_{OUT} = \left(1 + \dfrac{R1}{R2}\right) \cdot Vref$
NC (Fixed output)				**No connection**
V_{OUT}	5	3	2	**Output Voltage**

Functional Block Diagram
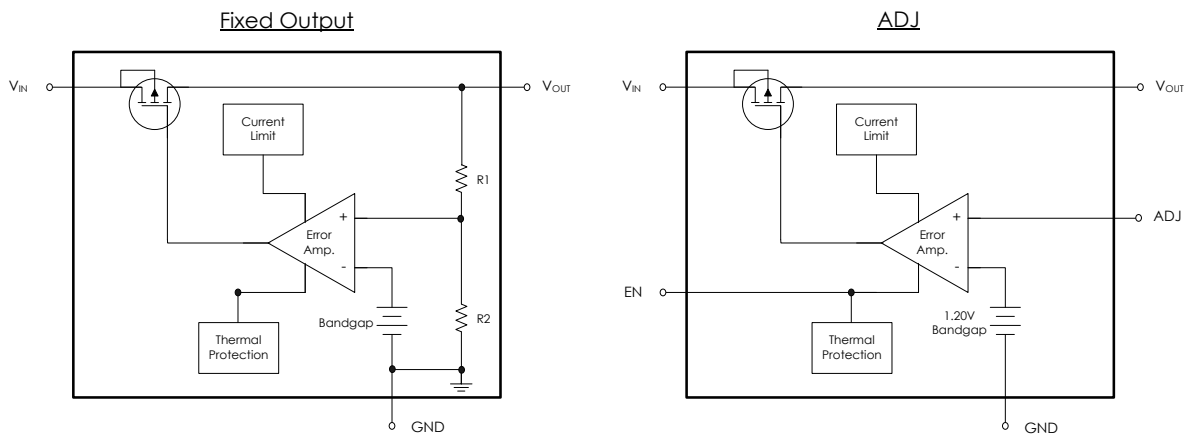
FIG.1. Functional Block Diagram of EMP8042

Absolute Maximum Ratings (Notes 1, 2)

V_{IN}, EN	-0.3V to 22V	Junction Temperature (T_J)	160°C
V_{OUT}	-0.3V to 13.2V	Lead Temperature (Soldering, 10 sec.)	260°C
Power Dissipation	(Note 5)	ESD Rating	
Storage Temperature Range	-65°C to 150°C	Human Body Model	2KV

Operating Ratings (Note 1, 2)

Supply Voltage (EMP8042B)	2.7V to 20V	Thermal Resistance (θ_{JA}, Note 3))	152°C/W (SOT-23-5)
Operating Temperature Range	-40°C to 85°C		101°C/W (SOT-89-3)
		Thermal Resistance (θ_{JC}, Note 4))	81°C/W (SOT-23-5)
			54°C/W (SOT-89-3)

Electrical Characteristics

T_A = 25°C, V_{OUT}(NOM)=5V; unless otherwise specified, all limits guaranteed for V_{IN} = V_{OUT} +1V, C_{IN} = C_{OUT} =1μF.

Symbol	Parameter	Conditions	Min	Typ (Note 6)	Max	Units
ΔV_{OTL}	Output Voltage Tolerance	I_{OUT} = 10mA $V_{OUT (NOM)}$ +1V ≤ V_{IN} ≤ 20V	-1		+1	% of $V_{OUT (NOM)}$
Vref	Reference voltage		1.188	1.200	1.212	
I_{OUT}	Maximum Output Current	Average DC Current Rating	150			mA
I_{LIMIT}	Output Current Limit		300			mA
I_Q	Supply Current	I_{OUT} = 0.1mA		13	50	μA
		I_{OUT} = 100mA		50	100	
		I_{OUT} = 150mA		80	130	
	Shutdown Supply Current	V_{OUT} = 0V, EN = GND		1	5	
V_{DO}	Dropout Voltage V_{OUT}=5.0V (Note. 7)	I_{OUT} = 30mA		135		mV
		I_{OUT} = 100mA		500		
		I_{OUT} = 150mA		780		
ΔV_{OUT}	Line Regulation	I_{OUT} = 1mA, (V_{OUT} + 1V) ≤ V_{IN} ≤ 20V		0.1		%
	Load Regulation	0.1mA ≤ I_{OUT} ≤ 100mA		0.5		%
e_n	Output Voltage Noise	I_{OUT}=10mA,10Hz ≤ f ≤ 100kHz V_{OUT} = 5.0V		800		μV_{RMS}
V_{EN}	EN Input Threshold	V_{IH}, (V_{OUT} + 1V) ≤ V_{IN} ≤ 20V	1.0			V
		V_{IL}, (V_{OUT} + 1V) ≤ V_{IN} ≤ 20V			0.3	
I_{EN}	EN Input Bias Current	EN = GND or V_{IN}		0.1		μA
T_{SD}	Thermal Shutdown Temperature			160		℃
	Thermal Shutdown Hysteresis			30		
t_{ON}	Start-Up Time	C_{OUT} = 1.0μF, V_{OUT} at 90% of Final Value		500		μs

Note 1: Absolute maximum ratings indicate limits beyond which damage may occur.

Note 2: All voltages are in respect to the potential of the ground pin.

Note 3: θ_{JA} is measured in the natural convection at T_A=25℃ on a high effectively thermal conductivity test board (2 layers, 2S0P).

Note 4: θ_{JC} represents the resistance between the chip and the top of the package case.

Note 5: Maximum power dissipation for the device is calculated using the following equation:

$$P_D = \frac{T_{J(MAX)} - T_A}{\theta_{JA}}$$

Where $T_J(MAX)$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction-to-ambient thermal resistance. For example, for the SOT-89-3 package θ_{JA}=101°C/W, $T_J(MAX)$=160°C and using T_A=25°C, the maximum power dissipation is 1.33W.
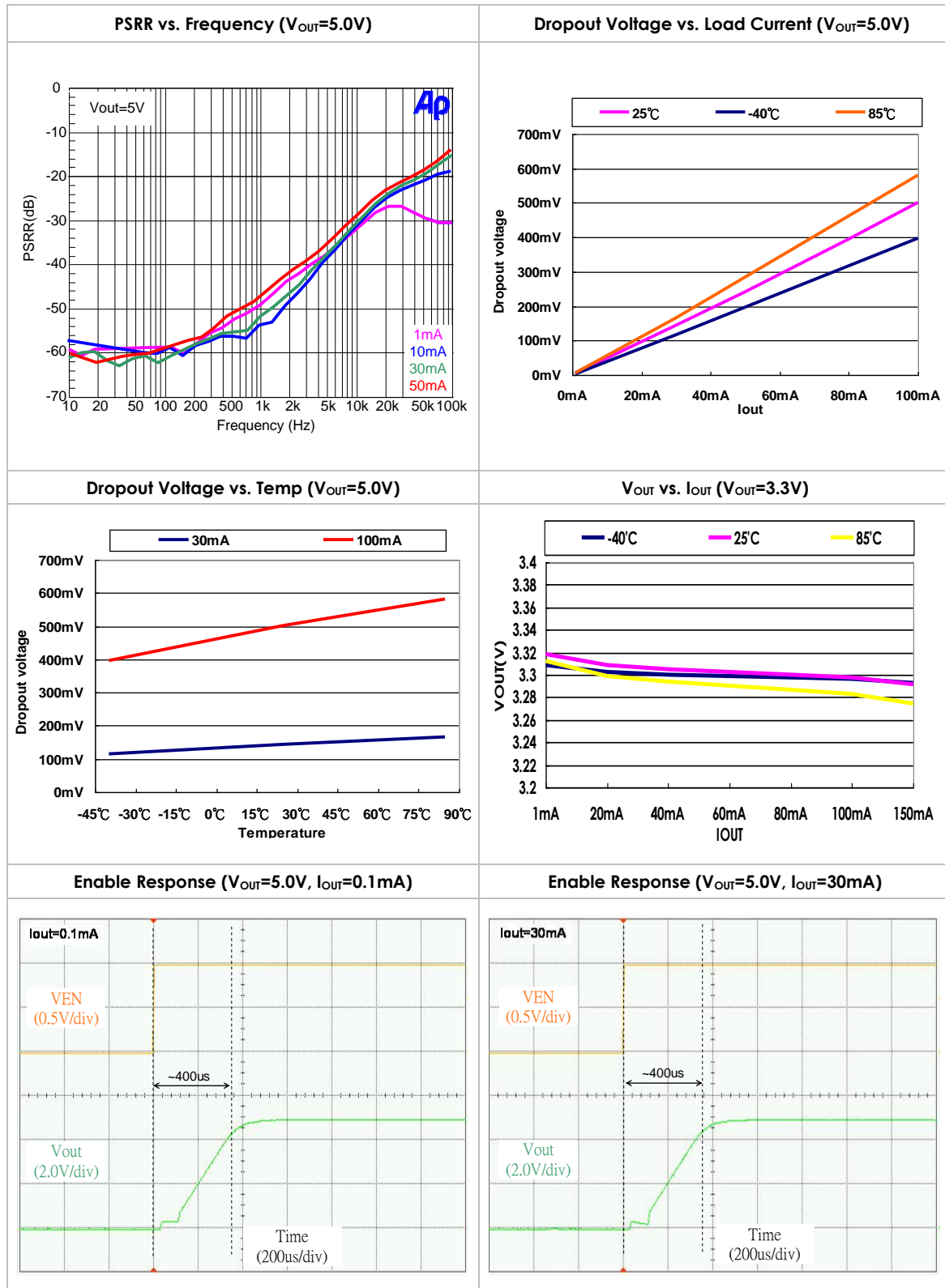The derating factor $(-1/\theta_{JA})$=-9.9mW/°C. Below 25°C the power dissipation figure can be increased by 9.9mW per degree and similarly decreased by this factor for temperatures above 25°C.

Note 6: Typical values represent the most likely parametric norm.

Note 7: Dropout voltage is measured by reducing V_{IN} until V_{OUT} drops to 98% its nominal value.

Typical Performance Characteristics

Unless otherwise specified, $V_{IN} = V_{OUT\ (NOM)} + 1V$, V_{OUT}=5V, $C_{IN} = C_{OUT} = 1.0\mu F$, $T_A = 25°C$

PSRR vs. Frequency (V_{OUT}=5.0V)

Dropout Voltage vs. Load Current (V_{OUT}=5.0V)

Dropout Voltage vs. Temp (V_{OUT}=5.0V)

V_{OUT} vs. I_{OUT} (V_{OUT}=3.3V)

Enable Response (V_{OUT}=5.0V, I_{OUT}=0.1mA)

Enable Response (V_{OUT}=5.0V, I_{OUT}=30mA)

Typical Performance Characteristics (cont.)

Unless otherwise specified, $V_{IN} = V_{OUT (NOM)} + 1V$, V_{OUT}=5V, $C_{IN} = C_{OUT}$ = 1.0μF, T_A = 25°C

ESMT
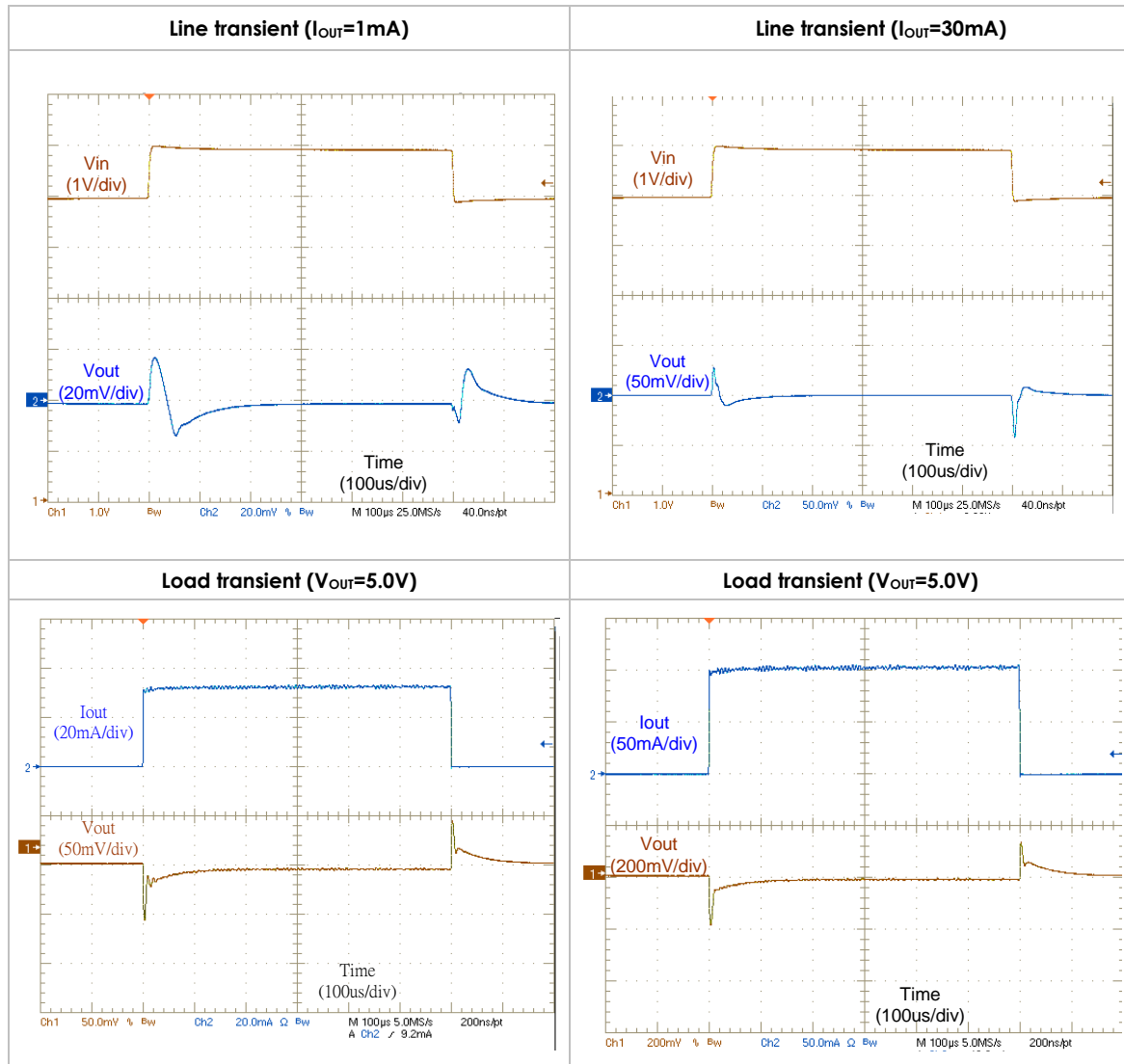
Application Information

General Description

Referring to Fig.1 as shown in the Functional Block Diagram section, the EMP8042 adopts the classical regulator topology in which negative feedback control is used to perform the desired voltage regulating function. The negative feedback is formed by using feedback resistors (R1, R2) to sample the output voltage for the non-inverting input of the error amplifier, whose inverting input is set to the bandgap reference voltage. By the virtue of its high open-loop gain, the error amplifier operates to ensure that the sampled output feedback voltage at its non-inverting input is virtually equal to the preset bandgap reference voltage.

The error amplifier compares the voltage difference at its inputs and produces an appropriate driving voltage to the P-channel MOS pass transistor to control the amount of current reaching the output. If there are changes in the output voltage due to load changes, the feedback resistors register such changes to the non-inverting input of the error amplifier. The error amplifier then adjusts its driving voltage to maintain virtual short between its two input nodes under all loading conditions. In a nutshell, the regulation of the output voltage is achieved as a direct result of the error amplifier keeping its input voltages equal. This negative feedback control topology is further augmented by the shutdown, the fault detection, and the temperature and current protection circuitry.

Output Voltage Setting

The output voltage of EMP8040 can be adjusted by a resistive divider according to the following formula:

$$V_{OUT} = V_{REF} * \left(1 + \frac{R_1}{R_2}\right) = 1.2 * \left(1 + \frac{R_1}{R_2}\right)$$

The resistive divider senses the fraction of the output voltage as shown in page 1 typical application circuit. The recommended value for R2 is in the range of 200K~500KΩ.

Output Capacitor

The EMP8042 is specially designed for use with ceramic output capacitors of as low as 1.0μF to take advantage of the savings in cost and space as well as the superior filtering of high frequency noise. Capacitors of higher value or other types may be used, but it is important to make sure its equivalent series resistance (ESR) is restricted to less than 0.5Ω. The use of larger capacitors with smaller ESR values is desirable for applications involving large and fast input or output transients, as well as for situations where the application systems are not physically located immediately adjacent to the battery power source. Typical ceramic capacitors suitable for use with the EMP8042 are X5R and X7R. The X5R and the X7R capacitors are able to maintain their capacitance values to within ±20% and ±10%, respectively, as the temperature increases.

No-Load Stability

The EMP8042 is capable of stable operation during no-load conditions, a mandatory feature for some applications such as CMOS RAM keep-alive operations.

Input Capacitor

A minimum input capacitance of 1µF is required for EMP8042. The capacitor value may be increased without limit. Improper workbench set-ups may have adverse effects on the normal operation of the regulator. A case in point is the instability that may result from long supply lead inductance coupling to the output through the gate capacitance of the pass transistor. This will establish a pseudo LCR network, and is likely to happen under high current conditions or near dropout. A 10µF tantalum input capacitor will dampen the parasitic LCR action thanks to its high ESR. However, cautions should be exercised to avoid regulator short-circuit damage when tantalum capacitors are used, for they are prone to fail in short-circuit operating conditions.

Power Dissipation and Thermal Shutdown

Thermal overload results from excessive power dissipation that causes the IC junction temperature to increase beyond a safe operating level. The EMP8042 relies on dedicated thermal shutdown circuitry to limit its total power dissipation. An IC junction temperature T_J exceeding 160°C will trigger the thermal shutdown logic, turning off the P-channel MOS pass transistor. The pass transistor turns on again after the junction cools off by about 30°C. When continuous thermal overload conditions persist, this thermal shutdown action then results in a pulsed waveform at the output of the regulator. The concept of thermal resistance θ_{JA} (°C/W) is often used to describe an IC junction's relative readiness in allowing its thermal energy to dissipate to its ambient air. An IC junction with a low thermal resistance is preferred because it is relatively effective in dissipating its thermal energy to its ambient, thus resulting in a relatively low and desirable junction temperature. The relationship between θ_{JA} and T_J is as follows:

$$T_J = \theta_{JA} \times (P_D) + T_A$$

T_A is the ambient temperature, and P_D is the power generated by the IC and can be written as:

$$P_D = I_{OUT} (V_{IN} - V_{OUT})$$

As the above equations show, it is desirable to work with ICs whose θ_{JA} values are small such that T_J does not increase strongly with P_D. To avoid thermally overloading the EMP8042, refrain from exceeding the absolute maximum junction temperature rating of 160°C under continuous operating conditions. Overstressing the regulator with high loading currents and elevated input-to-output differential voltages can increase the IC die temperature significantly.
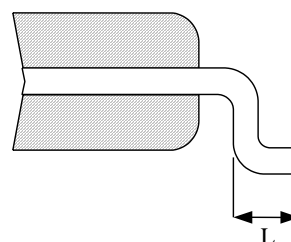
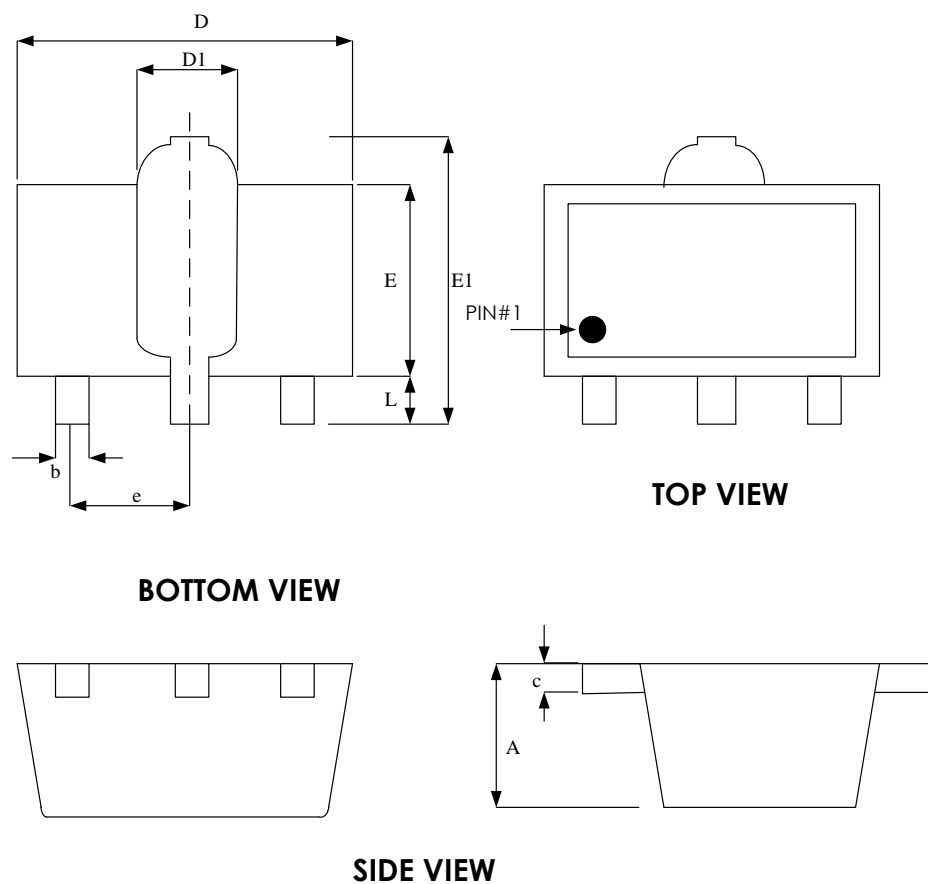**Package Outline Drawing**
SOT-23-5
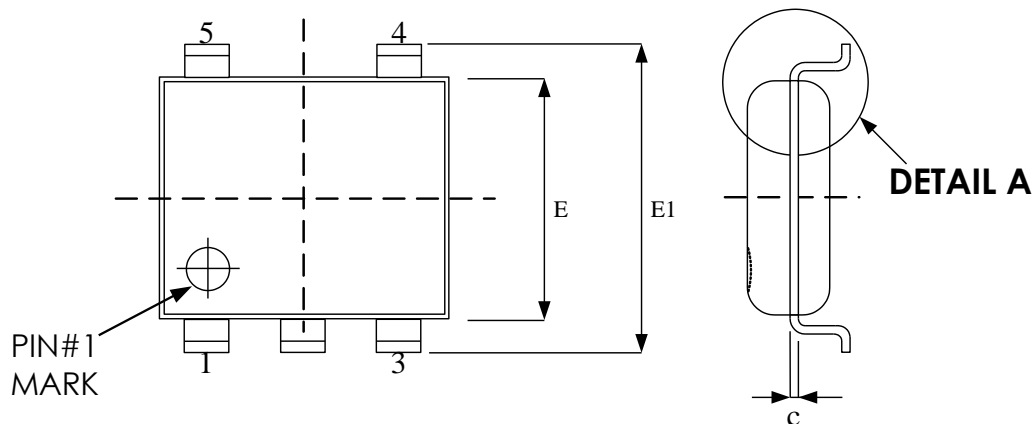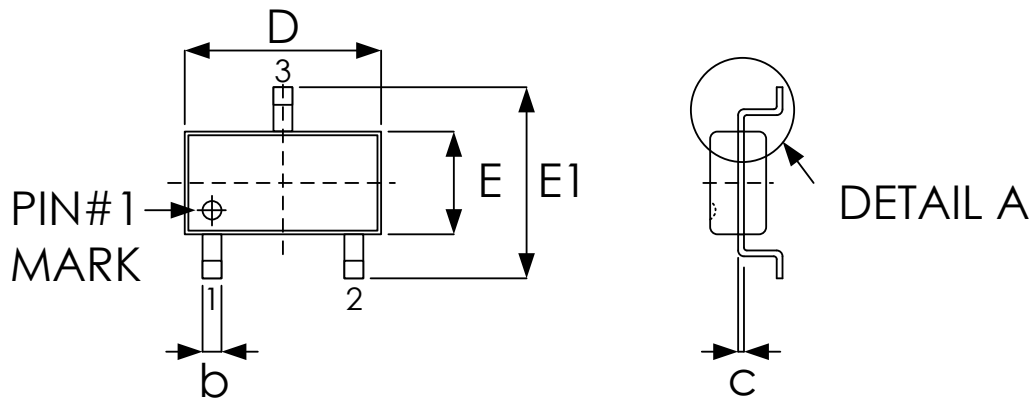

TOP VIEW
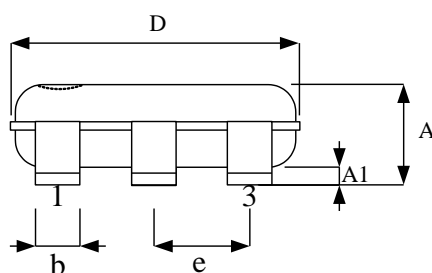
SIDE VIEW   DETAIL A

Symbol	Dimension in mm	
	Min.	Max.
A	0.90	1.45
A1	0.00	0.15
b	0.30	0.50
c	0.08	0.25
D	2.70	3.10
E	1.40	1.80
E1	2.60	3.00
e	0.95 BSC	
L	0.30	0.60

Package Outline Drawing
SOT-89-3

TOP VIEW

BOTTOM VIEW

SIDE VIEW

Symbol	Dimension in mm	
	Min	Max
A	1.4	1.6
b	0.4	0.56
c	0.35	0.41
D	4.4	4.6
D1	1.5	1.83
E	2.29	2.6
E1	3.94	4.25
e	1.50 BSC	
L	0.89	1.2

Package Outline Drawing
SOT-23-3

TOP VIEW
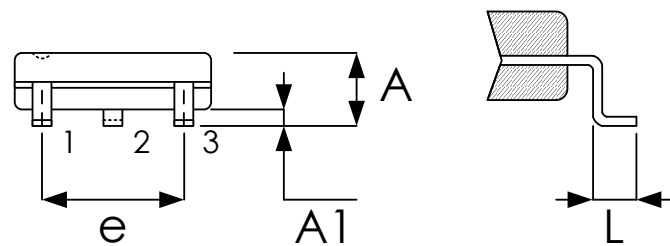
SIDE VIEW   DETAIL A

Symbol	Dimension in mm	
	Min.	Max.
A	0.90	1.45
A1	0.00	0.15
b	0.30	0.50
c	0.08	0.25
D	2.70	3.10
E	1.40	1.80
E1	2.60	3.00
e	1.90 BSC	
L	0.30	0.60

Revision History

Revision	Date	Description
0.1	2010.08.27	Original
1.0	2011.02.23	1. Skip "Preliminary" 2. Page1 revise "Typical Application" 3. Page2 add SOT-23-5 package 4. Page3 add SOT-23-5 "Pin Functions"
1.1	2011.12.12	1) Added ADJ output voltage option 2) Modified 100mA output driving capacity to 150mA. 3) Modified the output voltage accuracy is based on Iout=10mA this condition. 4) Added Iout=150mA spec. into electrical characteristics table.
1.2	2012.04.20	1) Added the typical value of supply current I_Q=13uA at Iout=0.1mA. 2) Updated the maximum value of supply current I_Q=50uA at Iout=0.1mA. 3) Updated the package outline drawing.
1.3	2012.08.31	1) Added the typical value of shutdown supply current I_Q=1uA at EN=GND. 2) Added the EN input Threshold.
1.4	2013.10.16	Updated the package outline drawing.
1.5	2017.06.26	Added EMP8042B series product.
1.6	2018.05.18	Added output voltage setting information.
1.7	2018.10.05	1) Modified General Description. 2) Modified Typical Application circuit. 3) Added Vout Absolute Maximum Ratings.
1.8	2022.02.09	Delete EMP8042 series product